

AMIETE – ET

Time: 3 Hours

DECEMBER 2014

Max. Marks: 100

PLEASE WRITE YOUR ROLL NO. AT THE SPACE PROVIDED ON EACH PAGE IMMEDIATELY AFTER RECEIVING THE QUESTION PAPER.

NOTE: There are 9 Questions in all.

- Question 1 is compulsory and carries 20 marks. Answer to Q.1 must be written in the space provided for it in the answer book supplied and nowhere else.
- The answer sheet for the Q.1 will be collected by the invigilator after 45 minutes of the commencement of the examination.
- Out of the remaining EIGHT Questions answer any FIVE Questions. Each question carries 16 marks.
- Any required data not explicitly given, may be suitably assumed and stated.

Q.1 Choose the correct or the best alternative in the following: (2×10)

a. A low-loss transmission line filled only with dielectric medium has a velocity factor on the order of

- (A) 1.02 (B) 1.65
(C) 0.56 (D) 0.65

b. The standing wave ratio of a pure travelling wave is

- (A) Unity (B) Infinite
(C) $\lambda/2$ (D) λ

c. Whenever two or more modes have the same cut-off frequency, they are said to be

- (A) TE₁₁ mode (B) TM₀₁ mode
(C) Degenerative mode (D) Dominant mode

d. List two microwave devices using faraday rotation principles

- (A) Modulator & Isolator (B) Modulator & Power Limiter
(C) Circulator & Modulator (D) Circulator & Isolator

e. Coupling parameters of directional coupler are

- (A) Insertion loss & Isolation (B) Coupling coefficient & Directivity
(C) Both (A) & (B) (D) None of these

f. The parameters on which bunching depend on

- (A) Drift space should be properly adjusted
(B) DC anode voltage
(C) Signal amplitude should be such that proper bunching takes place
(D) All of these

- g. The factors reducing efficiency of IMPATT diode are
- (A) Space charge effect & Reverse saturation current effect
 - (B) High frequency skin effect & Ionization saturation effect
 - (C) Both (A) & (B)
 - (D) None of these
- h. Some materials like GaAs exhibit negative differential mobility, when biased above a threshold value of the electric field. This behaviour is called
- (A) Field Effect
 - (B) Magnetron Effect
 - (C) Transferred Electron Effect
 - (D) Both (A) and (B)
- i. The main purpose of slotted section with line carriage is
- (A) Measure the VSWR and standing wave pattern
 - (B) Reflection coefficient
 - (C) Return loss measurement
 - (D) All of these
- j. The ratio of total power radiated to total power accepted at its input is
- (A) Phase Velocity Factor
 - (B) Radiation Efficiency
 - (C) Standing Wave Ratio
 - (D) Both (A) & (C)

Answer any FIVE Questions out of EIGHT Questions.
Each question carries 16 marks.

- Q.2** a. A transmission line has the following parameters: (6)
 $R=2 \text{ ohm/m}$ $G=0.5 \text{ mmho/m}$ $f=1 \text{ GHz}$
 $L=8 \text{ nH/m}$ $C=0.23 \text{ pF}$
 Calculate: (i) the characteristics impedance (ii) the propagation constant.
- b. Derive the equation for determining the reflection coefficient at any point along the line. (10)
- Q.3** a. An air-filled waveguide with cross section $2 \times 1 \text{ cm}$ transport energy in the TE_{10} mode at the rate of 0.5 hp . The impressed frequency is 30 GHz . What is the peak value of the electric field occurring? (6)
- b. Show that the power transmission derived from the Poynting's theory is same as from the circuit theory for an ordinary transmission line. (10)
- Q.4** a. Explain the Waveguide Corners, Bends and Twists in waveguide components. (8)
- b. Derive the expression for the resonant frequency and the unloaded Q_0 of cavity resonator. (8)

- Q.5** a. Draw the equivalent circuits of Tunnel Diodes and Calculate gain equations of a tunnel diode amplifier. (10)
- b. Draw equivalent circuit for a parametric amplifier and explain the working operation of it. (6)
- Q.6** a. Show that the gain bandwidth product is independent of frequency. (8)
- b. Explain the working operation of Reflex Klystron with neat Schematic. (8)
- Q.7** a. Draw the equivalent circuit for resonator of a magnetron and derive the expressions for Power output and efficiency. (10)
- b. A CFA operates under the following parameters: (6)
- Anode dc voltage : $V_{ao} = 2 \text{ kV}$
- Anode dc current : $I_{ao} = 1.5 \text{ A}$
- Electron Efficiency: $\eta_e = 20\%$
- RF input power: $P_{in} = 80 \text{ W}$
- Calculate: The induced RF power, Total RF output power,
Power gain in decibels.
- Q.8** a. Derive expression for Quality Factor 'Q' of Micro-Strip Lines and show that it is approximately the reciprocal of the dielectric loss tangent θ . (10)
- b. Describe about Coplanar Strip Losses. (6)
- Q.9** Write a detail note on the following:- (2×8)
- (a) MMIC Fabrication Techniques
- (b) Hybrid Integrated – Circuit Fabrication